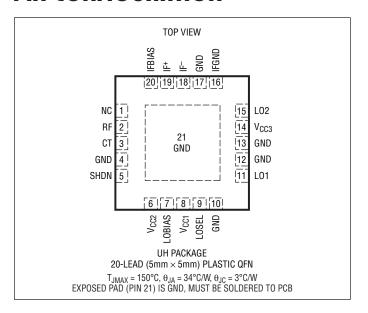
### **ABSOLUTE MAXIMUM RATINGS**

#### (Note 1)

Mixer Supply Voltage (V <sub>CC1</sub> , V <sub>CC2</sub> )	)3.8V
LO Switch Supply Voltage (V <sub>CC3</sub> ).	
IF Supply Voltage (IF+, IF-)	5.5V
Shutdown Voltage (SHDN)	$-0.3V$ to $V_{CC} + 0.3V$
LO Select Voltage (LOSEL)	$-0.3V$ to $V_{CC} + 0.3V$
LO1, LO2 Input Power (0.2GHz to	2GHz)9dBm
LO1, LO2 Input DC Voltage	±0.5V
RF Input Power (0.2GHz to 2GHz)	15dBm
RF Input DC Voltage	±0.1V
Operating Temperature Range	40°C to 85°C
Storage Temperature Range	65°C to 150°C
Junction Temperature (T <sub>J</sub> )	150°C

# PIN CONFIGURATION



### ORDER INFORMATION

LEAD FREE FINISH	TAPE AND REEL	PART MARKING	PACKAGE DESCRIPTION	TEMPERATURE RANGE
LTC5540IUH#PBF	LTC5540IUH#TRPBF	5540	20-Lead (5mm × 5mm) Plastic QFN	-40°C to 85°C

Consult LTC Marketing for parts specified with wider operating temperature ranges. Consult LTC Marketing for information on non-standard lead based finish parts.

For more information on lead free part marking, go to: http://www.linear.com/leadfree/

For more information on tape and reel specifications, go to: http://www.linear.com/tapeandreel/

# **AC ELECTRICAL CHARACTERISTICS** $V_{CC} = 3.3V$ , $V_{CCIF} = 3.3V$ , SHDN = Low, $T_A = 25^{\circ}C$ , $P_{L0} = 0$ dBm, unless otherwise noted. Test circuit shown in Figure 1. (Notes 2, 3, 4)

PARAMETER	CONDITIONS	MIN TYP	MAX	UNITS
LO Input Frequency Range		700 to 1200	700 to 1200	
RF Input Frequency Range	Low-Side LO High-Side LO	800 to 1300 600 to 1100		
IF Output Frequency Range	Requires External Matching	5 to 500		MHz
RF Input Return Loss	$Z_0 = 50\Omega$ , 600MHz to 1300MHz	>12	>12	
LO Input Return Loss	$Z_0 = 50\Omega$ , 700MHz to 1200MHz	>12	>12	
IF Output Return Loss	Requires External Matching	>12	>12	
LO Input Power	f <sub>L0</sub> = 700MHz to 1200MHz	-4 0	-4 0 6	
LO to RF Leakage	f <sub>L0</sub> = 700MHz to 1200MHz	<-30	<-30	
LO to IF Leakage	f <sub>L0</sub> = 700MHz to 1200MHz	<-37	<-37	
LO Switch Isolation	L01 Selected, $700 \text{MHz} < f_{L0} < 1200 \text{MHz}$ L02 Selected, $700 \text{MHz} < f_{L0} < 1200 \text{MHz}$	>50 >47		
RF to LO Isolation	f <sub>RF</sub> = 600MHz to 1300MHz	>55	>55	
RF to IF Isolation	f <sub>RF</sub> = 600MHz to 1300MHz	>37	>37	
	,	,		5540f

High-Side LO Downmixer Application: RF = 600MHz to 1100MHz, IF = 190MHz,  $f_{LO} = f_{RF} + f_{IF}$ 

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
Conversion Gain	RF = 700MHz RF = 900MHz RF = 1100MHz	6.3	7.6 7.9 7.9		dB dB dB
Conversion Gain Flatness	RF = 900 ±30MHz, LO = 1090MHz, IF=190 ±30MHz		±0.20		dB
Conversion Gain vs Temperature	$T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}, \text{ RF} = 900\text{MHz}$		-0.008		dB/°C
Input 3 <sup>rd</sup> Order Intercept	RF = 700MHz RF = 900MHz RF = 1100MHz	23.4	26.5 25.9 23.8		dBm dBm dBm
SSB Noise Figure	RF = 700MHz RF = 900MHz RF = 1100MHz		10.0 9.9 10.4	11.7	dB dB dB
SSB Noise Figure Under Blocking	$f_{RF} = 900MHz$ , $f_{LO} = 1090MHz$ , $f_{BLOCK} = 800MHz$ , $P_{BLOCK} = 5dBm$		16.2		dB
$2LO - 2RF$ Output Spurious Product $(f_{RF} = f_{LO} - f_{IF}/2)$	$f_{RF} = 995MHz$ at $-10dBm$ , $f_{LO} = 1090MHz$ , $f_{IF} = 190MHz$		-70		dBc
$3LO - 3RF$ Output Spurious Product $(f_{RF} = f_{LO} - f_{IF}/3)$	$f_{RF} = 1026.67MHz$ at $-10dBm$ , $f_{LO} = 1090MHz$ , $f_{IF} = 190MHz$		<del>-</del> 75		dBc
Input 1dB Compression	RF = 900MHz, V <sub>CCIF</sub> = 3.3V RF = 900MHz, V <sub>CCIF</sub> = 5V		11 14.5		dBm dBm

Low-Side LO Downmixer Application: RF = 800MHz-1300MHz, IF = 190MHz,  $f_{LO} = f_{RF} - f_{IF}$ 

PARAMETER	CONDITIONS	MIN TYP	MAX	UNITS
Conversion Gain	RF = 900MHz RF = 1100MHz RF = 1300MHz	7.0 7.8 8.0		dB dB dB
Conversion Gain Flatness	RF = 900MHz ±30MHz, LO = 710MHz, IF = 190 ±30MHz	±0.33		dB
Conversion Gain vs Temperature	$T_A = -40$ °C to 85°C, RF = 900MHz	-0.007		dB/°C
Input 3rd Order Intercept	RF = 900MHz RF = 1100MHz RF = 1300MHz	24.4 24.1 23.6		dBm dBm dBm
SSB Noise Figure	RF = 900MHz RF = 1100MHz RF = 1300MHz	10.6 10.5 10.3		dB dB dB
SSB Noise Figure Under Blocking	$f_{RF} = 900MHz$ , $f_{LO} = 710MHz$ , $f_{IF} = 190MHz$ , $f_{BLOCK} = 1000MHz$ , $P_{BLOCK} = 5dBm$	16.7		dB
2RF – 2LO Output Spurious Product $(f_{RF} = f_{LO} + f_{IF/2})$	$f_{RF}$ = 805MHz at -10dBm, $f_{LO}$ = 710MHz, $f_{IF}$ = 190MHz	-61.5		dBc
$3RF - 3LO$ Output Spurious Product $(f_{RF} = f_{LO} + f_{IF/3})$	$f_{RF} = 773.33 MHz$ at $-10 dBm$ , $f_{LO} = 710 MHz$ , $f_{IF} = 190 MHz$	-68		dBc
Input 1dB Compression	$RF = 900MHz, V_{CCIF} = 3.3V$ $RF = 900MHz, V_{CCIF} = 5V$	11 14		dBm dBm

# DC ELECTRICAL CHARACTERISTICS

 $V_{CC}$  = 3.3V,  $V_{CCIF}$  = 3.3V, SHDN = Low,  $T_A$  = 25°C, unless otherwise

noted. Test circuit shown in Figure 1. (Note 2)

PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
Power Supply Requirements (V <sub>CC</sub> , V <sub>CCIF</sub> )		·				
V <sub>CC</sub> Supply Voltage (Pins 6, 8 and 14)			3.1	3.3	3.5	V
V <sub>CCIF</sub> Supply Voltage (Pins 18 and 19)			3.1	3.3	5.3	V
V <sub>CC</sub> Supply Current (Pins 6 + 8 + 14) V <sub>CCIF</sub> Supply Current (Pins 18 + 19) Total Supply Current (V <sub>CC</sub> + V <sub>CCIF</sub> )				97 96 193	116 120 236	mA mA mA
Total Supply Current – Shutdown	SHDN = High				500	μА
Shutdown Logic Input (SHDN) Low = On, Hig	h = Off					
SHDN Input High Voltage (Off)			3			V
SHDN Input Low Voltage (On)					0.3	V
SHDN Input Current	-0.3V to V <sub>CC</sub> + 0.3V		-20		30	μΑ
Turn On Time				1		μs
Turn Off Time				1.5		μs
LO Select Logic Input (LOSEL) Low = LO1 Se	lected, High = LO2 Selected	·				
LOSEL Input High Voltage			3			V
LOSEL Input Low Voltage					0.3	V
LOSEL Input Current	-0.3V to V <sub>CC</sub> + 0.3V		-20		30	μА
LO Switching Time				50		ns

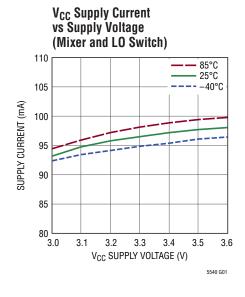
**Note 1:** Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. Exposure to any Absolute Maximum Rating condition for extended periods may affect device reliability and lifetime.

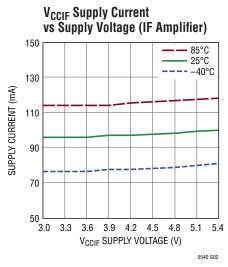
**Note 2:** The LTC5540 is guaranteed functional over the operating temperature range from  $-40^{\circ}$ C to 85°C.

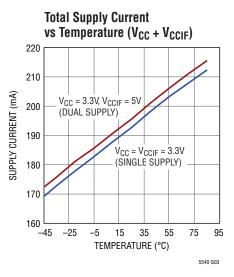
**Note 3:** SSB Noise Figure measured with a small-signal noise source, bandpass filter and 6dB matching pad on RF input, bandpass filter and 6dB matching pad on the LO input, and no other RF signals applied.

**Note 4:** LO switch isolation is measured at the IF output port at the IF frequency with  $f_{LO1}$  and  $f_{LO2}$  offset by 2MHz.

# TYPICAL DC PERFORMANCE CHARACTERISTICS SHDN = Low, Test circuit shown in Figure 1.





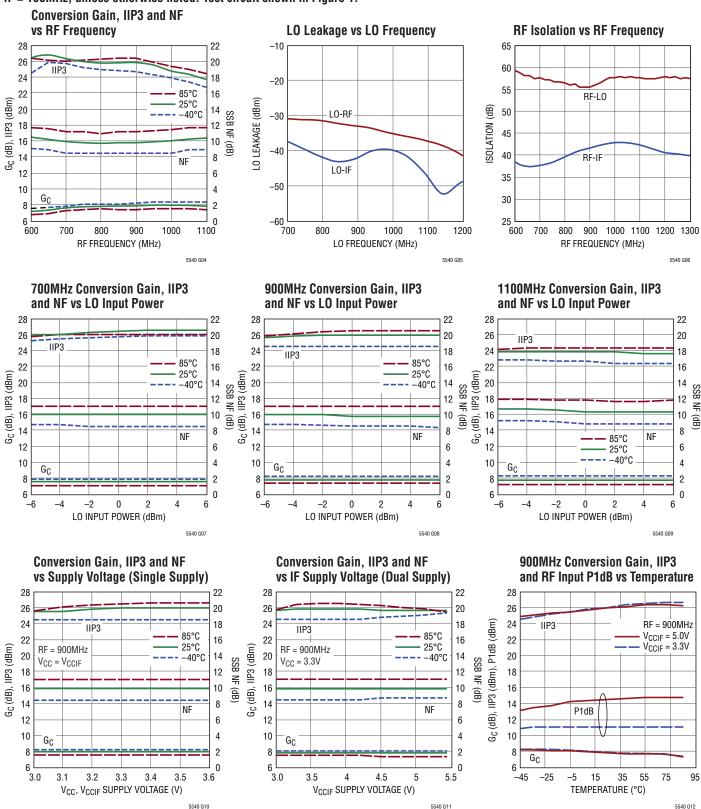


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LINEAD TECHNOLOGY

# TYPICAL AC PERFORMANCE CHARACTERISTICS High-Side LO

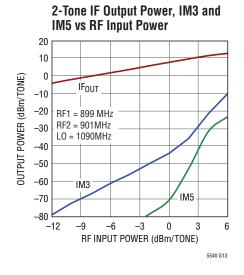
 $V_{CC}$  = 3.3V,  $V_{CCIF}$  = 3.3V, SHDN = Low,  $T_A$  = 25°C,  $P_{LO}$  = 0dBm,  $P_{RF}$  = -3dBm (-3dBm/tone for two-tone IIP3 tests,  $\Delta f$  = 2MHz), IF = 190MHz, unless otherwise noted. Test circuit shown in Figure 1.

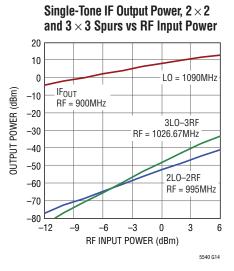


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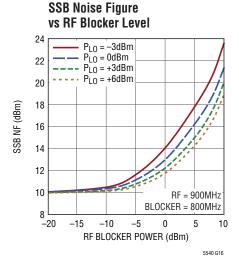
# TYPICAL AC PERFORMANCE CHARACTERISTICS High-Side LO (continued)

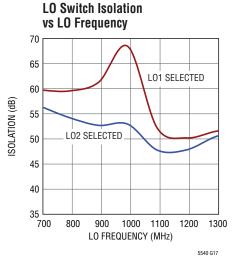
 $V_{CC}$  = 3.3V,  $V_{CCIF}$  = 3.3V, SHDN = Low,  $T_A$  = 25°C,  $P_{LO}$  = 0dBm,  $P_{RF}$  = -3dBm (-3dBm/tone for two-tone IIP3 tests,  $\Delta f$  = 2MHz), IF = 190MHz, unless otherwise noted. Test circuit shown in Figure 1.

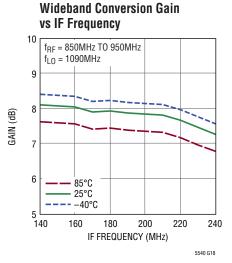


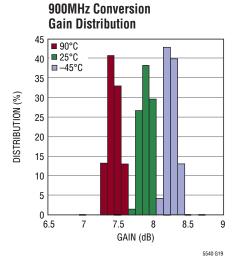


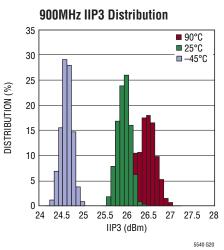


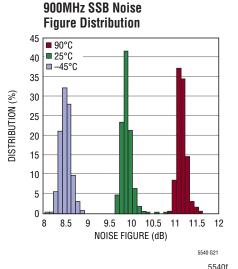








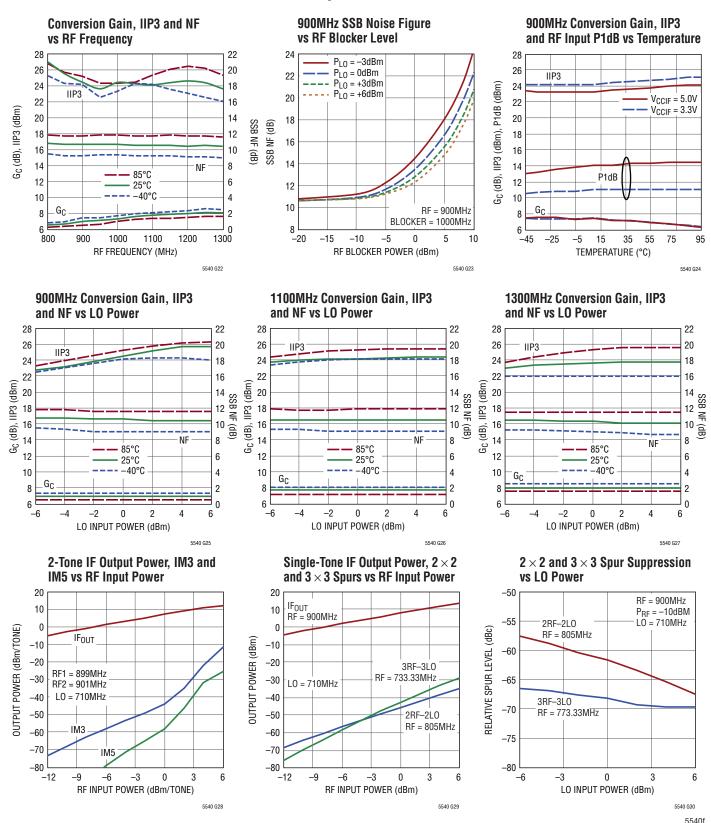






# TYPICAL AC PERFORMANCE CHARACTERISTICS Low-Side LO

 $V_{CC}$  = 3.3V,  $V_{CCIF}$  = 3.3V, SHDN = Low,  $T_A$  = 25°C,  $P_{LO}$  = 0dBm,  $P_{RF}$  = -3dBm (-3dBm/tone for two-tone IIP3 tests,  $\Delta f$  = 2MHz), IF = 190MHz, unless otherwise noted. Test circuit shown in Figure 1.



#### PIN FUNCTIONS

**NC (Pin 1):** This pin is not connected internally. It can be left floating, connected to ground or to  $V_{CC}$ .

RF (Pin 2): Single-Ended Input for the RF Signal. This pin is internally connected to the primary side of the RF input transformer, which has low DC resistance to ground. A series DC-blocking capacitor should be used to avoid damage to the integrated transformer. The RF input is impedance matched, as long as the selected LO input is driven with a OdBm ±6dB source between 0.7GHz and 1.2GHz.

**CT (Pin 3):** RF Transformer Secondary Center-Tap. This pin may require a bypass capacitor to ground. See the Applications Information section. This pin has an internally generated bias voltage of 1.2V. It must be DC-isolated from ground and  $V_{CC}$ .

**GND** (Pins 4, 10, 12, 13, 17, Exposed Pad Pin 21): Ground. These pins must be soldered to the RF ground plane on the circuit board. The exposed pad metal of the package provides both electrical contact to ground and good thermal contact to the printed circuit board.

**SHDN (Pin 5):** Shutdown Pin. When the input voltage is less than 0.3V, the internal circuits supplied through pins 6, 8, 14, 18 and 19 are enabled. When the input voltage is greater than 3V, all circuits are disabled. Typical input current is less than  $10\mu A$ . This pin must not be allowed to float.

 $V_{CC2}$  (Pin 6) and  $V_{CC1}$  (Pin 8): Power Supply Pins for the LO Buffer and Bias Circuits. These pins are internally connected and must be externally connected to a regulated 3.3V supply, with bypass capacitors located close to the pin. Typical current consumption is 97mA.

**LOBIAS (Pin 7):** This Pin Allows Adjustment of the LO Buffer Current. Typical DC voltage is 2.2V.

**LOSEL (Pin 9):** LO1/LO2 Select Pin. When the input voltage is less than 0.3V, the LO1 port is selected. When the input voltage is greater than 3V, the LO2 port is selected. Typical input current is  $11\mu A$  for LOSEL = 3.3V. This pin must not be allowed to float.

**LO1 (Pin 11) and LO2 (Pin 15):** Single-Ended Inputs for the Local Oscillators. These pins are internally biased at 0V and require external DC blocking capacitors. Both inputs are internally matched to  $50\Omega$ , even when the chip is disabled (SHDN = high).

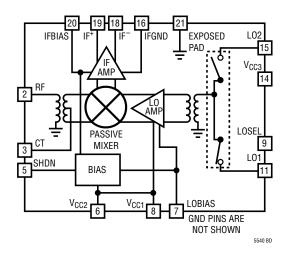
**V<sub>CC3</sub> (Pin 14):** Power Supply Pin for the LO Switch. This pin must be connected to a regulated 3.3V supply and bypassed to ground with a capacitor near the pin. Typical DC current consumption is less than 100μA.

**IFGND (Pin 16):** DC Ground Return for the IF Amplifier. This pin must be connected to ground to complete the IF amplifier's DC current path. Typical DC current is 96mA.

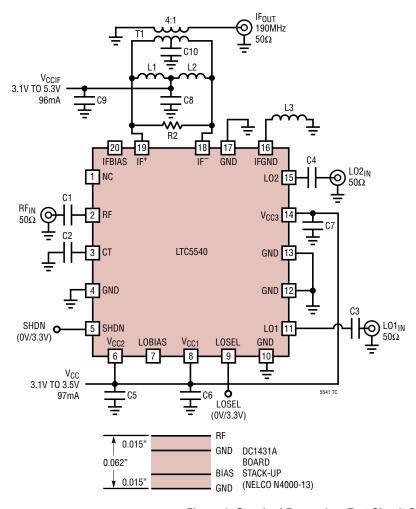
**IF**<sup>-</sup> (**Pin 18**) and **IF**<sup>+</sup> (**Pin 19**): Open-Collector Differential Outputs for the IF Amplifier. These pins must be connected to a DC supply through impedance matching inductors, or a transformer center-tap. Typical DC current consumption is 48mA into each pin.

**IFBIAS (Pin 20):** This Pin Allows Adjustment of the IF Amp Current. Typical DC voltage is 2.1V.

# **BLOCK DIAGRAM**



# **TEST CIRCUIT**



L1, L2 vs IF Frequencies			
IF (MHz)	L1, L2 (nH)		
140	270		
190	150		
240	100		
380	33		
450	22		

REF DES	VALUE	SIZE	COMMENTS
C3, C4	100pF	0402	AVX
C6, C7, C8	22pF	0402	AVX
C5, C9	1μF	0603	AVX
C10	1000pF	0402	AVX
L1, L2	150nH	0603	Coilcraft 0603CS
L3	30nH	0603	Coilcraft 0603CS
R2	2.05k	0402	
T1 (Alternate)	TC4-1W-7ALN+ (WBC4-6TLB)		Mini-Circuits (Coilcraft)
HIGH-SIDE LO			
C1	5.6pF	0402	AVX
C2	1.5pF	0402	AVX
LOW-SIDE LO			•
C1, C2	100pF	0402	AVX
			•

Figure 1. Standard Downmixer Test Circuit Schematic (190MHz IF)

5540



#### Introduction

The LTC5540 consists of a high linearity passive double-balanced mixer core, IF buffer amplifier, high speed single-pole double-throw (SPDT) LO switch, LO buffer amplifier and bias/enable circuits. See Pin Functions section for a description of each pin function. The RF and LO inputs are single-ended. The IF output is differential. Low-side or high-side LO injection can be used. The evaluation circuit, shown in Figure 1, utilizes bandpass IF output matching and an IF transformer to realize a  $50\Omega$  single-ended IF output. The evaluation board layout is shown in Figure 2.

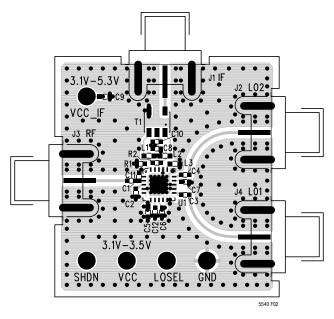


Figure 2. Evaluation Board Layout

#### **RF** Input

The mixer's RF input, shown in Figure 3, is connected to the primary winding of an integrated transformer. A  $50\Omega$  match is realized when a series capacitor, C1, is connected to the RF input. C1 is also needed for DC blocking if the RF source has DC voltage present, since the primary side of the RF transformer is DC-grounded internally. The DC resistance of the primary is approximately  $5\Omega$ .

The secondary winding of the RF transformer is internally connected to the passive mixer. The center-tap of the transformer secondary is connected to pin 3 (CT) to allow the connection of bypass capacitor, C2. The value of C2 is LO frequency-dependent. C2 should be located within

2mm of pin 3 for proper high-frequency decoupling. The nominal DC voltage on the CT pin is 1.2V.

For the RF input to be properly matched, the selected LO input must be driven. The values of C1 and C2 can be chosen to optimize the performance for high-side or low-side LO (see the table in Figure 1). For high-side applications, a broadband input match is realized with C1 = 5.6pF. The measured input return loss is shown in Figure 4 for LO frequencies of 700MHz, 1090MHz and 1200MHz. As shown in Figure 4, the RF input impedance is dependent on LO frequency, although a single value of C1 is adequate to cover a wide RF range.

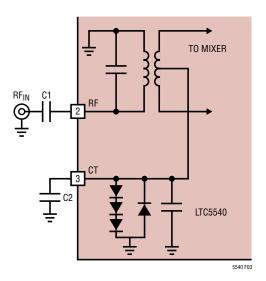


Figure 3. RF Input Schematic

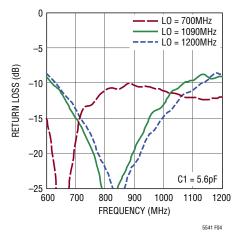


Figure 4. RF Input Return Loss

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The RF input impedance and input reflection coefficient, versus RF frequency, is listed in Table 1. The reference plane for this data is pin 2 of the IC, with no external matching, and the LO is driven at 1090MHz.

Table 1. RF Input Impedance and S11 (at Pin 2, No External Matching, LO Input Driven at 1090MHz)

RF	RF RF INPUT	S-	l1
(GHz)	IMPEDANCE	MAG	ANGLE
0.4	14.7 + j19.7	0.6	133.8
0.5	18.1 + j24.4	0.6	122.9
0.6	23.1 + j27.7	0.5	113.4
0.7	29.9 + j30.6	0.4	102.3
0.8	39.0 + j32.9	0.4	88.2
0.9	52.8 + j31.7	0.3	67.8
1.0	67.3 + j15.4	0.2	34.3
1.1	55.2 – j13.4	0.1	-61.4
1.2	36.2 – j11.2	0.2	-133.5
1.3	31.2 – j4.8	0.2	-162.4
1.4	29.8 – j0.2	0.3	-179.2

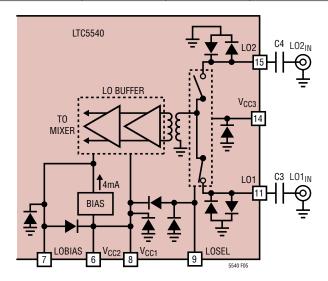


Figure 5. LO Input Schematic

#### **LO Inputs**

The mixer's LO input circuit, shown in Figure 5, consists of an integrated SPDT switch, a balun transformer, and a two-stage high-speed limiting differential amplifier to drive the mixer core. The LTC5540's LO amplifiers are optimized for the 0.7GHz to 1.2GHz LO frequency range. LO frequencies above or below this frequency range may be used with degraded performance.

The LO switch is designed for high isolation and fast (<50ns) switching. This allows the use of two active synthesizers in frequency-hopping applications. If only one synthesizer is used, then the unused LO input may be grounded. The LO switch is powered by  $V_{CC3}$  (Pin 14) and controlled by the LOSEL logic input (Pin 9). The LO1 and LO2 inputs are always  $50\Omega$ -matched when  $V_{CC}$  is applied to the chip, even when the chip is shutdown. The DC resistance of the selected LO input is approximately  $23\Omega$  and the unselected input is approximately  $50\Omega$ . A logic table for the LO switch is shown in Table 2. Measured LO input return loss is shown in Figure 6.

Table 2. LO Switch Logic Table

LOSEL	ACTIVE LO INPUT
Low	L01
High	L02

The LO amplifiers are powered by  $V_{CC1}$  and  $V_{CC2}$  (pin 8 and pin 6). When the chip is enabled (SHDN = low), the internal bias circuit provides a regulated 4mA current to the amplifier's bias input, which in turn causes the amplifiers to draw approximately 80mA of DC current. This 4mA reference is also connected to LOBIAS (Pin 7) to allow modification of the amplifier's DC bias current for special applications. The recommended application circuits require no LO amplifier bias modification, so this pin should be left open-circuited.

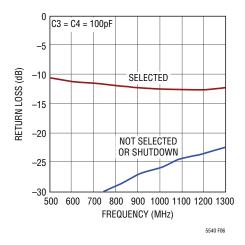


Figure 6. LO Input Return loss



The nominal LO input level is 0dBm although the limiting amplifiers will deliver excellent performance over a ±6dBm input power range. LO input power greater than 6dBm may cause conduction of the internal ESD diodes. Series capacitors C3 and C4 optimize the input match and provide DC blocking.

The LO1 input impedance and input reflection coefficient, versus frequency, is shown in Table 3. The LO2 port is identical due to the symmetric device layout and packaging.

Table 3. LO1 Input Impedance vs Frequency (at Pin 11, No External Matching, LOSEL = Low)

FREQUENCY	INPUT		S11
(GHz)	IMPEDANCE	MAG	ANGLE
0.6	48.9 + j30.6	0.3	74.9
0.7	62.8 + j29.4	0.28	51.9
0.8	78.0 + j17.2	0.25	23.9
0.9	80.4 – j4.55	0.24	-6.5
1.0	68.3 – j20.5	0.23	-38.4
1.1	54.6 – j24.1	0.23	-66.3
1.2	44.7 – j22.3	0.24	-90.1
1.3	38.1 – j18.7	0.25	-110.5
1.4	33.8 – j14.9	0.26	-127.3

#### **IF Output**

The IF amplifier, shown in Figure 7, has differential open-collector outputs (IF+ and IF-), a DC ground return pin (IFGND), and a pin for modifying the internal bias (IFBIAS). The IF outputs must be biased at the supply voltage ( $V_{CCIF}$ ), which is applied through matching inductors L1 and L2. Alternatively, the IF outputs can be biased through the center tap of a transformer. Each IF output pin draws approximately 48mA of DC supply current (96mA total). Resistor R2 is used to improve the impedance match.

IFGND (pin 16) must be grounded or the amplifier will not draw DC current. Grounding through inductor L3 improves LO-IF and RF-IF leakage performance but is otherwise not necessary. High DC resistance in L3 will reduce the IF amplifier supply current, which will degrade RF performance.

For optimum single-ended performance, the differential IF outputs must be combined through an external IF

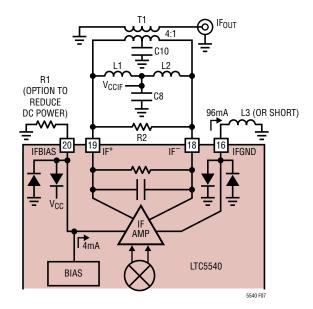


Figure 7. IF Amplifier Schematic with Bandpass Match

transformer or discrete IF balun circuit. The evaluation board (see Figures 1 and 2) uses a 4:1 ratio IF transformer for impedance transformation and differential to single-ended transformation. It is also possible to eliminate the IF transformer and drive differential filters or amplifiers directly.

The IF output impedance can be modeled as  $320\Omega$  in parallel with 2.3 pF at IF frequencies. An equivalent small-signal model (including bondwire inductance) is shown in Figure 8. Frequency-dependent differential IF output impedance is listed in Table 4. This data is referenced to the package pins (with no external components) and includes the effects of IC and package parasitics.

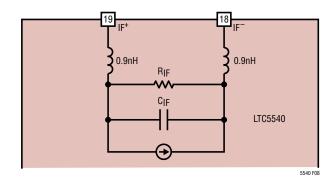


Figure 8. IF Output Small-Signal Model

INFAD

#### **Bandpass IF Matching**

The IF output can be matched for IF frequencies as low as 70MHz or as high as 500MHz using the bandpass IF matching shown in Figure 1 and Figure 7. L1 and L2 resonate with the internal IF output capacitance at the desired IF frequency. The value of L1, L2 is calculated as follows:

$$L1 = L2 = 1/[(2 \pi f_{|F})^2 \cdot 2 \cdot C_{|F}]$$

where C<sub>IF</sub> is the internal IF capacitance (listed in Table 4).

Values of L1 and L2 are tabulated in Figure 1 for various IF frequencies. For IF frequencies below 70MHz, the values of L1, L2 become unreasonably high and the lowpass topology shown in Figure 9 is preferred. Measured IF output return loss for bandpass IF matching is plotted in Figure 10.

Table 4. IF Output Impedance vs Frequency

FREQUENCY (MHz)	DIFFERENTIAL OUTPUT IMPEDANCE $(R_{IF}    X_{IF} (C_{IF}))$
70	674    -j1137 (2pF)
140	628    -j569 (2pF)
190	606    -j419 (2pF)
240	584    -j316 (2.1pF)
300	561    -j253 (2.1pF)
380	532    -j182 (2.3pF)
450	511    -j154 (2.3pF)

### **Lowpass IF Matching**

An alternative IF matching network shown in Figure 9 uses a lowpass topology, which provides excellent RF to IF and LO to IF isolation.  $V_{CCIF}$  is supplied through the center tap of the 4:1 transformer. A lowpass impedance transformation is realized by shunt elements R2 and C13 (in parallel with the internal R<sub>IF</sub> and C<sub>IF</sub>), and series inductors L1 and L2. Resistor R2 is used to reduce the IF output resistance, or it can be deleted for the highest conversion gain. The final impedance transformation to  $50\Omega$  is realized by transformer T1. The matching element values shown in Figure 9 are optimized for a wideband 30MHz-150MHz IF match. The demo board (see Figure 2) has been laid out to accommodate this matching topology with very few modifications.

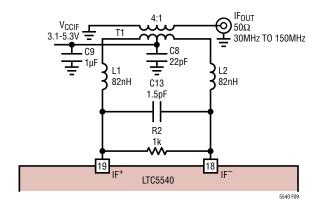


Figure 9. IF Output with Lowpass Matching

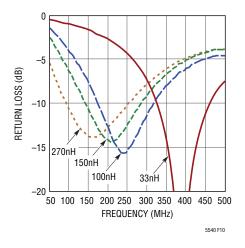


Figure 10. IF Output Return Loss - Bandpass Matching

#### **IF Amplifier Bias**

The IF amplifier delivers excellent performance with  $V_{CCIF} = 3.3V$ , which allows the  $V_{CC}$  and  $V_{CCIF}$  supplies to be common. With  $V_{CCIF}$  increased to 5V, the RF input P1dB increases by almost 3dB, at the expense of higher power consumption. Mixer performance at 900MHz is shown in Table 5 with  $V_{CCIF} = 3.3V$  and 5V. For the highest conversion gain, high-Q wire-wound chip inductors are recommended for L1 and L2, especially when using  $V_{CCIF} = 3.3V$ . Low-cost multilayer chip inductors may be substituted, with a slight reduction in conversion gain.

Table 5. Performance Comparison with  $V_{CCIF} = 3.3V$  and 5V (RF = 900MHz, High-Side LO, IF = 190MHz)

V <sub>CCIF</sub>	I <sub>CCIF</sub>	G <sub>C</sub>	P1dB	IIP3	NF
3.3V	96	7.9	11	25.9	9.9
5V	99	7.9	14.5	25.9	10.0



The IFBIAS pin (pin 20) is available for reducing the DC current consumption of the IF amplifier, at the expense of IIP3. This pin should be left open-circuited for optimum performance. The internal bias circuit produces a 4mA reference for the IF amplifier, which causes the amplifier to draw approximately 96mA. If resistor R1 is connected to pin 20 as shown in Figure 7, a portion of the reference current can be shunted to ground, resulting in reduced IF amplifier current. For example, R1 =  $1k\Omega$  will shunt away 1.5mA from pin 20 and the IF amplifier current will be reduced by 38% to approximately 59mA. The nominal, open-circuit DC voltage at pin 20 is 2.1V. Table 6 lists RF performance at 900MHz versus IF amplifier current.

Table 6. Mixer Performance with Reduced IF Amplifier Current (RF = 900MHz, High-Side LO, IF = 190MHz,  $V_{CC} = V_{CCIF} = 3.3V$ )

R1 (kΩ)	I <sub>CCIF</sub> (mA)	G <sub>C</sub> (dB)	IIP3 (dBm)	P1dB (dBm)	NF (dB)
OPEN	96	7.9	25.9	11.0	9.9
4.7	86	7.7	25.3	11.1	9.9
2.2	77	7.6	24.7	11.3	9.9
1	59	7.3	23.0	10.8	9.8

(RF = 900MHz, Low-Side LO, IF = 190MHz,  $V_{CC} = V_{CCIF} = 3.3V$ )

R1 (kΩ)	I <sub>CCIF</sub> (mA)	G <sub>C</sub> (dB)	IIP3 (dBm)	P1dB (dBm)	NF (dB)
OPEN	96	7.0	24.4	11.0	10.6
4.7	86	6.9	23.4	11.0	10.6
2.2	77	6.8	23.2	11.1	10.6
1	59	6.3	22.4	10.5	10.5

#### Shutdown Interface

Figure 11 shows a simplified schematic of the SHDN pin interface. To disable the chip, the SHDN voltage must be higher than 3.0V. If the shutdown function is not required, the SHDN pin should be connected directly to GND. The voltage at the SHDN pin should never exceed the power supply voltage ( $V_{CC}$ ) by more than 0.3V. If this should occur, the supply current could be sourced through the ESD diode, potentially damaging the IC.

The SHDN pin must be pulled high or low. If left floating, then the on/off state of the IC will be indeterminate. If a three-state condition can exist at the SHDN pin, then a pull-up or pull-down resistor must be used.

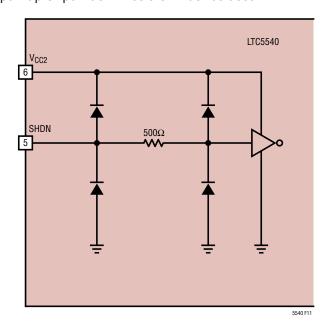


Figure 11. Shutdown Input Circuit

#### **Supply Voltage Ramping**

Fast ramping of the supply voltage can cause a current glitch in the internet ESD protection circuits. Depending on the supply inductance, this could result in a supply voltage transient that exceeds the maximum rating. A supply voltage ramp time of greater than 1ms is recommended.



PIN 1 NOTCH

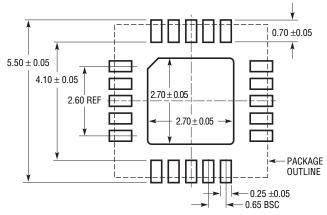
R = 0.30 TYP

BOTTOM VIEW—EXPOSED PAD

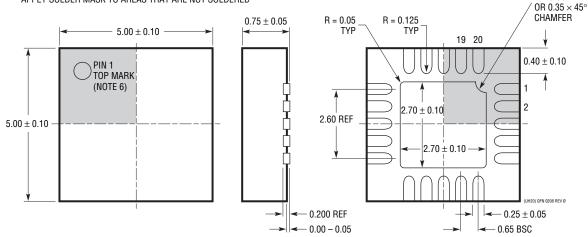
### PACKAGE DESCRIPTION

# $\begin{array}{c} \text{UH Package} \\ \text{20-Lead Plastic QFN (5mm} \times \text{5mm)} \end{array}$

(Reference LTC DWG # 05-08-1818 Rev Ø)



RECOMMENDED SOLDER PAD PITCH AND DIMENSIONS APPLY SOLDER MASK TO AREAS THAT ARE NOT SOLDERED



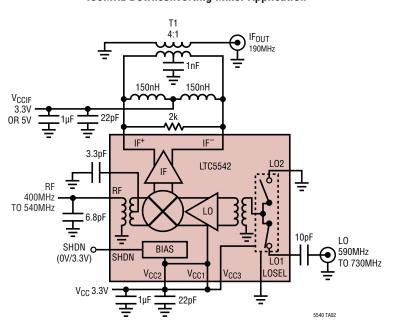
#### NOTE:

- 1. DRAWING IS NOT A JEDEC PACKAGE OUTLINE
- 2. DRAWING NOT TO SCALE
- 3. ALL DIMENSIONS ARE IN MILLIMETERS
- 4. DIMENSIONS OF EXPOSED PAD ON BOTTOM OF PACKAGE DO NOT INCLUDE MOLD FLASH. MOLD FLASH, IF PRESENT, SHALL NOT EXCEED 0.20mm ON ANY SIDE
- 5. EXPOSED PAD SHALL BE SOLDER PLATED
- 6. SHADED AREA IS ONLY A REFERENCE FOR PIN 1 LOCATION ON THE TOP AND BOTTOM OF PACKAGE

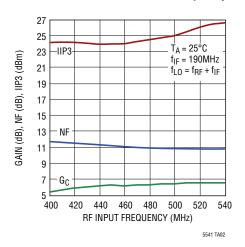


# TYPICAL APPLICATION

#### 450MHz Downconverting Mixer Application



#### Gain, NF and IIP3 vs RF Frequency



# **RELATED PARTS**

PART NUMBER	DESCRIPTION	COMMENTS	
Infrastructure			
LT5527	400MHz to 3.7GHz, 5V Downconverting Mixer	2.3dB Gain, 23.5dBm IIP3 and 12.5dB NF at 1900MHz, 5V/78mA Supply	
LT5557	400MHz to 3.8GHz, 3.3V Downconverting Mixer	2.9dB Gain, 24.7dBm IIP3 and 11.7dB NF at 1950MHz, 3.3V/82mA Supply	
LTC6400-X	300MHz Low Distortion IF Amp/ADC Driver	Fixed Gain of 8dB, 14dB, 20dB and 26dB; >36dBm OIP3 at 300MHz, Differential I/O	
LTC6401-X	140MHz Low Distortion IF Amp/ADC Driver	Fixed Gain of 8dB, 14dB, 20dB and 26dB; >40dBm OIP3 at 140MHz, Differential I/O	
LTC6416	2GHz 16-Bit ADC Buffer	40.25dBm OIP3 to 300MHz, Programmable Fast Recovery Output Clamping	
LTC6412	31dB Linear Analog VGA	35dBm OIP3 at 240MHz, Continuous Gain Range –14dB to 17dB	
LT5554	Ultralow Distort IF Digital VGA	48dBm OIP3 at 200MHz, 2dB to 18dB Gain Range, 0.125dB Gain Steps	
LT5575	700MHz to 2.7GHz Direct Conversion I/Q Demodulator	Integrated Baluns, 28dBm IIP3, 13dBm P1dB, 0.03dB I/Q Amplitude Match, 0.4° Phase Match	
LT5578	400MHz to 2.7GHz Upconverting Mixer	27dBm OIP3 at 900MHz, 24.2dBm at 1.95GHz, Integrated RF Transformer	
LT5579	1.5GHz to 3.8GHz Upconverting Mixer	27.3dBm OIP3 at 2.14GHz, NF = 9.9dB, 3.3V Supply, Single-Ended LO and RF Ports	
LTC5598	5MHz to 1.6GHz I/Q Modulator	27.7dBm OIP3 at 140MHz, 22.9dBm at 900MHz, -161.2dBm/Hz Noise Floor	
RF Power Detectors			
LT5534	50MHz to 3GHz Log RF Power Detector with 60dB Dynamic Range	±1dB Output Variation over Temperature, 38ns Response Time, Log Linear Response	
LT5537	Wide Dynamic Range Log RF/IF Detector	Low Frequency to 1GHz, 83dB Log Linear Dynamic Range	
LT5570	2.7GHz Mean-Squared Detector	±0.5dB Accuracy Over Temperature and >50dB Dynamic Range, 500ns Rise Time	
LT5581	6GHz Low Power RMS Detector	40dB Dynamic Range, ±1dB Accuracy Over Temperature, 1.5mA Supply Current	
ADCs			
LTC2208	16-Bit, 130Msps ADC	78dBFS Noise Floor, >83dB SFDR at 250MHz	
LTC2262-14	14-Bit, 150Msps ADC Ultralow Power	72.8dB SNR, 88dB SFDR, 149mW Power Consumption	
LTC2242-12	12-Bit, 250Msps ADC	65.4dB SNR, 78dB SFDR, 740mW Power Consumption	
		5540f	